

**General Description**

Battery Packs and Battery-powered portable equipment applications.  
It's mainly suitable for use as a load switch in battery powered applications and protection in battery packs.

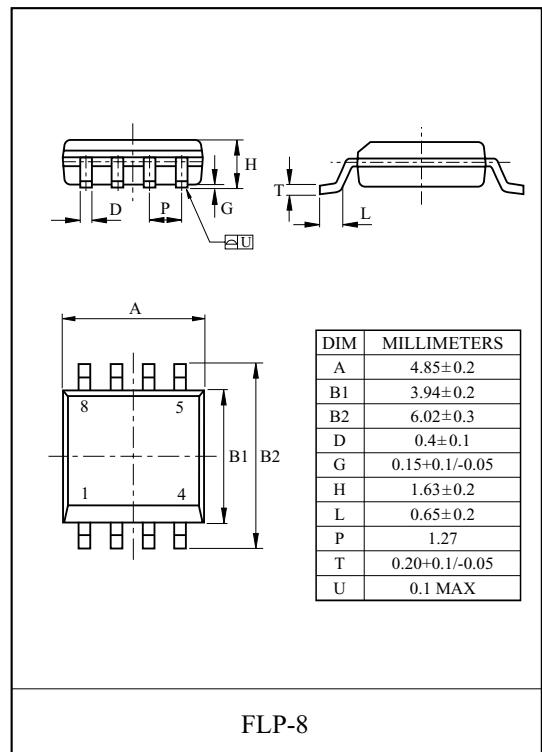
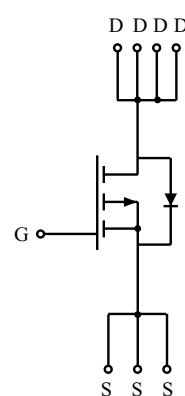
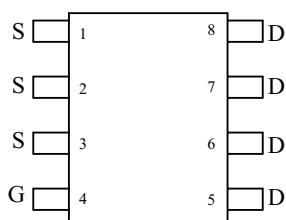
**FEATURES**

- $V_{DSS} = -20V$ ,  $I_D = -6.5A$ .
- Drain-Source ON Resistance.
  - :  $R_{DS(ON)} = 35m\Omega$  (Max.) @  $V_{GS} = -4.5V$ .
  - :  $R_{DS(ON)} = 60m\Omega$  (Max.) @  $V_{GS} = -2.5V$ .

**MAXIMUM RATING (Ta=25 °C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Drain-Source Voltage	$V_{DSS}$	-20	V
Gate-Source Voltage	$V_{GSS}$	$\pm 12$	V
Drain Current	DC	$I_D$ *	A
	Pulsed (Note2)	$I_{DP}$	
Drain Power Dissipation	Ta=25	2.5	W
	Ta=100	1.0	
Maximum Junction Temperature	$T_j$	150	
Storage Temperature Range	$T_{stg}$	-55 ~ 150	
Thermal Resistance, Junction to Ambient	$R_{thJA}$ *	50	/W

\* : Surface Mounted on 1 "x 1 "Board, t = 10sec.

**PIN CONNECTION (TOP VIEW)**

# KMA6D5P20Q

## ELECTRICAL CHARACTERISTICS (Ta=25 °C)

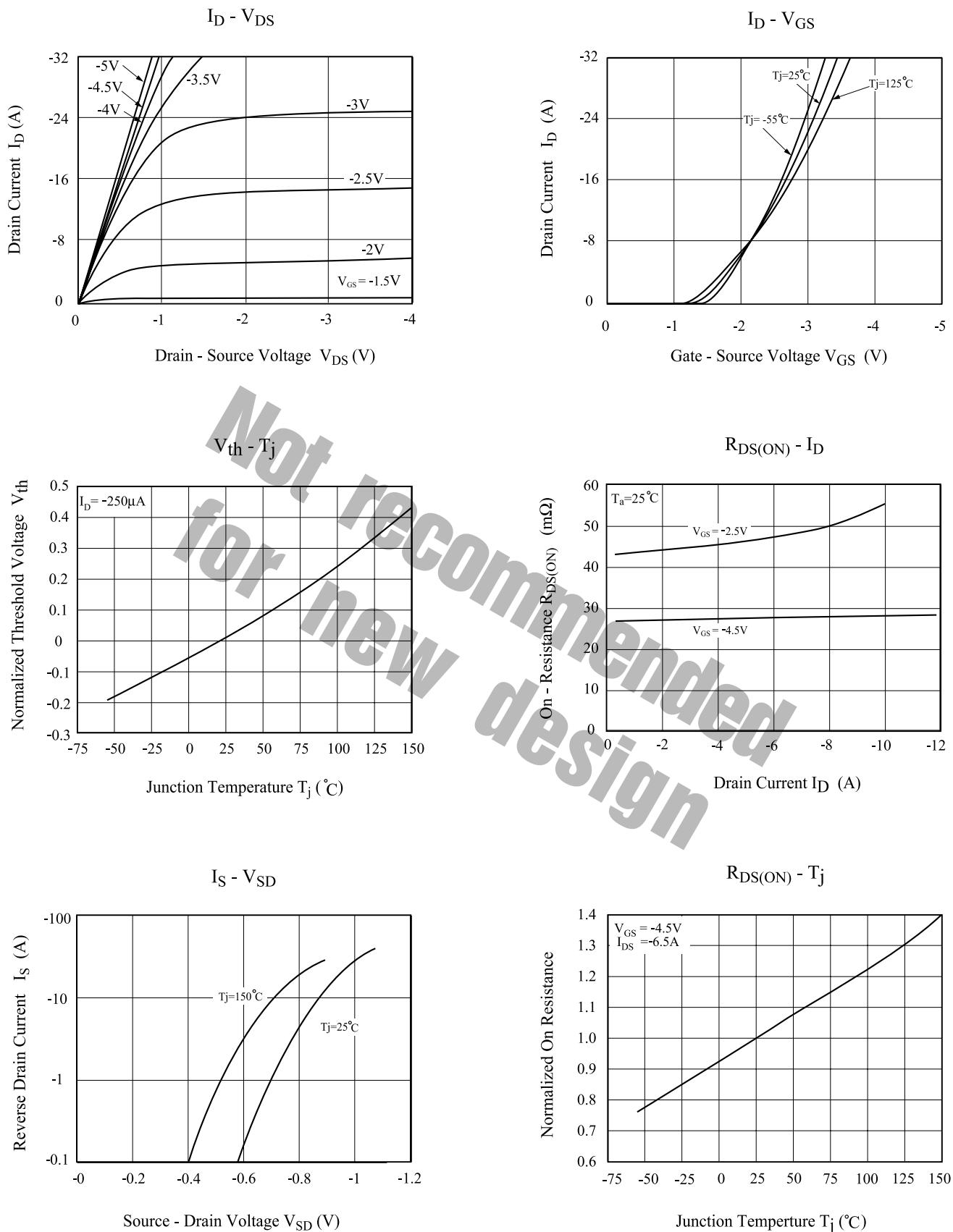
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =-250 μA, V <sub>GS</sub> =0V,	-20	-	-	V
Drain Cut-off Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V,	-	-	-1	μA
Gate Threshold Voltage	V <sub>th</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250 μA	-0.6	-	-	V
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	-	-	±100	nA
Drain-Source ON Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-6.5A (Note 2)	-	27	35	m
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-5.0A (Note 2)	-	46	60	
<b>Dynamic</b> (Note 3)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-6.5A V <sub>GS</sub> =-4.5V (Fig.1)	-	13.6	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	2.3	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	5.5	-	
Turn-on Delay time	t <sub>d(on)</sub>	V <sub>DD</sub> =-10V, R <sub>L</sub> =1.5 , R <sub>G</sub> =6 (Fig.2)	-	10	-	ns
Turn-on Rise time	t <sub>r</sub>		-	35	-	
Turn-off Delay time	t <sub>d(off)</sub>		-	38	-	
Turn-off Fall time	t <sub>f</sub>		-	50	-	
<b>Source-Drain Diode Ratings</b>						
Continuous Source Current	I <sub>S</sub>	V <sub>GS</sub> <V <sub>th</sub> (Note 1)	-	-	-1.7	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-6.5A, V <sub>GS</sub> =0V (Note 2)	-	-	-1.5	V

Note 1) Based on thermal dissipation from junction to ambient while mounted on a 1 "x 1 "PCB Board.

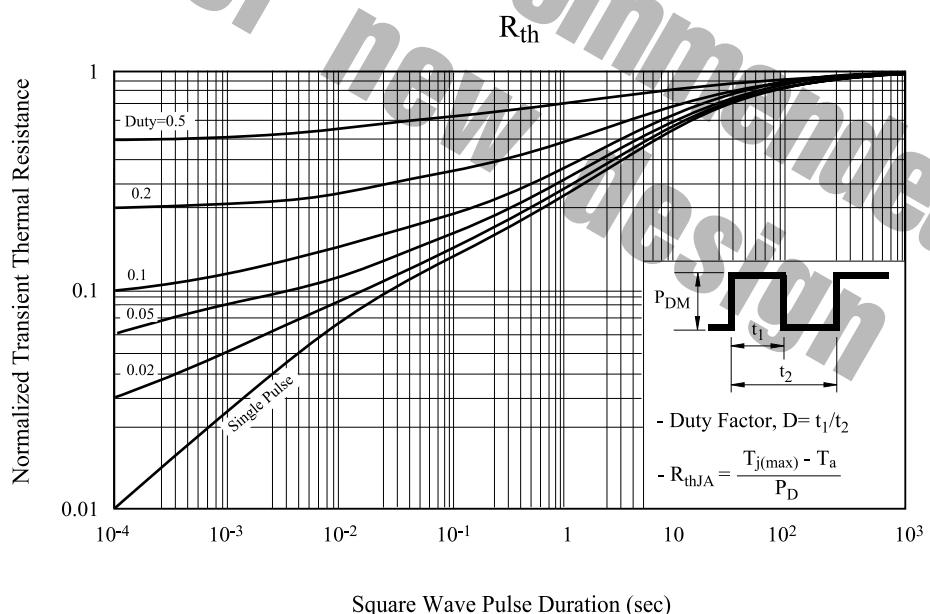
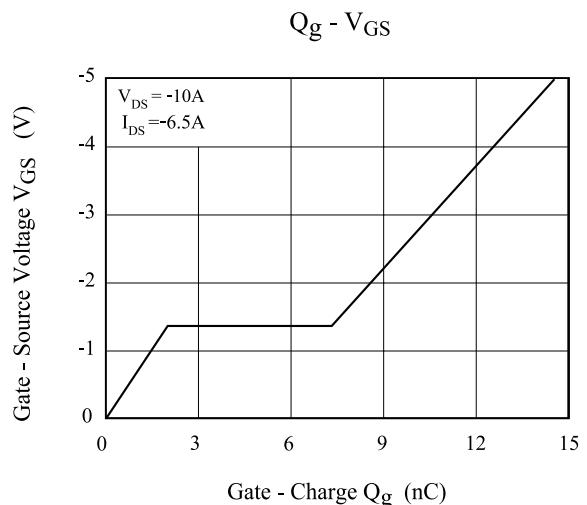
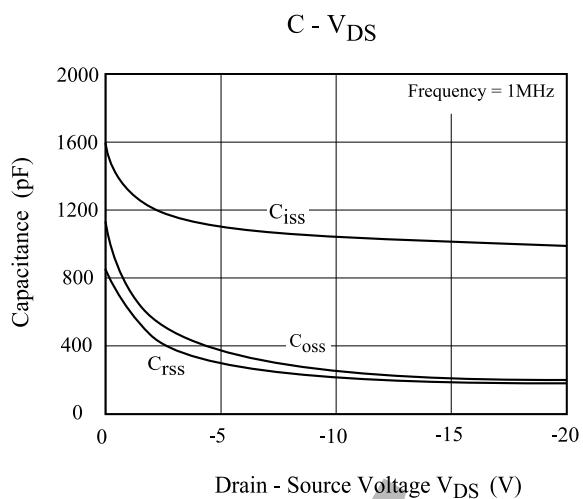
Note 2) Pulse test : Pulse width 300μs.

Note 3) Guaranteed by design, not subject to production testing.

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Fig. 1 Gate Charge

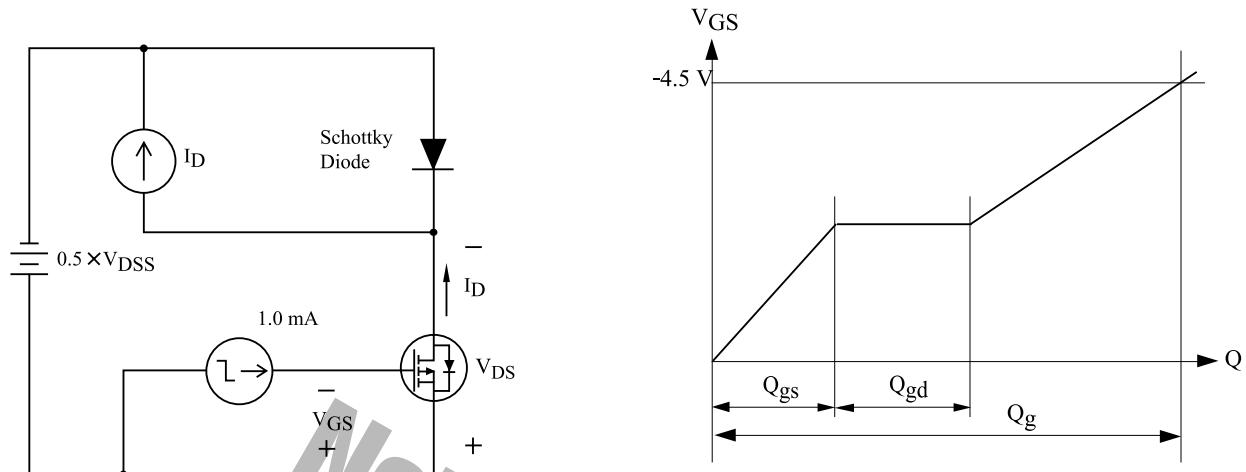


Fig. 2 Resistive Load Switching

